

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, TRANSISTOR, NPN GERMANIUM,
POWER TYPE 2N326

This amendment forms a part of MIL-S-19500/408 dated 26 February 1968, and is approved for use by all Departments and Agencies of the Department of Defense.

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TABLE I, subgroup 3, base emitter voltage (nonsaturated), minimum limits column:
Delete "0.5".

TABLE I, subgroup 3, base emitter voltage (nonsaturated), minimum limits column:
Delete "0.75".

CONCLUDING MATERIAL

Custodians:

Army - ER
Navy - EC
Air Force - 11

Preparing activity:

Army - ER

Agent:

DLA - ES

(Project 5961-1088)

Review activities:

Army - ER, MI
Air Force - 11, 17, 85
DLA - ES
Navy - EC, SH

User activities:

Army - ER, SM
Navy - AS, CG, MC, OS
Air Force - 19